NSN 5961-00-169-4599

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View Online at https://aerobasegroup.com/nsn/5961-00-169-4599 **Inclosure Material:** Ceramic **Overall Length:** 0.120 inches **Overall Height:** 0.125 inches **Overall Diameter:** 0.285 inches **End Application:** General application electronics (gen-ap-e) **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 1.50 amperes source cutoff current **Power Rating Per Characteristic:** 19.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:**

Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 4 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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